

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
1	BRS	L1	2241	359/241-245,321.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:24	
2	BRS	L5	2151	(macrocycle)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:22	
3	BRS	L7	0	1 and 4 and 5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:21	
4	BRS	L10	0	1 and 5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:23	
5	BRS	L4	4	(molecular adj archit\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:24	

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
6	BRS	L11	4	molecu\$3 adj archit\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:25	
7	BRS	L12	180	365/151,64.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:26	
8	BRS	L13	9	12 and (macrocycle)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:27	
9	BRS	L14	142	257/2.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:27	
10	BRS	L15	1	14 and (macrocycle)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:29	

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
11	BRS	L16	94966	switch\$3 adj device\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:31	
12	BRS	L17	869	16 and (molecule)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:32	
13	BRS	L18	628	17 and (substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:32	
14	BRS	L19	355	18 and (semiconductor)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:32	
15	BRS	L20	13	19 and (macrocycle)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 10:33	